

# STTH1506TPI

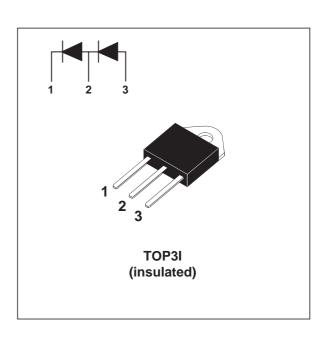
# Tandem 600V Hyperfast Rectifer

#### **MAJOR PRODUCTS CHARACTERISTICS**

I <sub>F(AV)</sub>	15 A
V <sub>RRM</sub>	600 V (in series)
Tj (max)	150 °C
V <sub>F</sub> (max)	2.6 V
I <sub>RM</sub> (typ.)	4.8 A

#### **FEATURES AND BENEFITS**

- Especially suited as boost diode in continuous mode power factor correctors and hard switching conditions.
- Designed for high di/dt operation. Hyperfast recovery current to compete with GaAs devices. Allows downsizing of mosfet and heatsinks.
- Internal ceramic insulated devices with equal thermal conditions for both 300V diodes.
- Insulation (2500V RMS) allows placement on same heatsink as mosfet and flexible heatsinking on common or separate heatsink.
- Matched diodes for typical PFC application without need for voltage balance network.
- C = 7pF



#### **DESCRIPTION**

The TURBOSWITCH "H" is an ultra high performance diode composed of two 300V dice in series. TURBOSWITCH "H" family drastically cuts losses in the associated MOSFET when run at high  $dl_F/dt$ .

#### ABSOLUTE RATINGS (limiting values for both diodes in series)

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	600	V
I <sub>F(RMS)</sub>	RMS forward current	26	А
I <sub>FSM</sub>	Surge non repetitive forward current	130	А
T <sub>stg</sub>	Storage temperature range	-65 +150	°C
Tj	Maximum operating junction temperatu	+ 150	°C

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#### THERMAL AND POWER DATA

Symbol	Parameter	Test conditions	Value	Unit
R <sub>th (j-c)</sub>	Junction to case	Per diode	2.9	°C/W
R <sub>th (c)</sub>		Coupling	0.3	
R <sub>th (j-c)</sub>	Junction to case	Total	1.6	
P <sub>1</sub>	Conduction power dissipation for both diodes	$I_{F(AV)} = 15 \text{ A}  \delta = 0.5$ Tc = 70°C	50	W

### STATIC ELECTRICAL CHARACTERISTICS (for both diodes)

Symbol	Parameter	Tests Conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> *	Reverse leakage cur-	$V_R = V_{RRM}$	Tj = 25°C			20	μΑ
	rent		Tj = 125°C		30	200	
V <sub>F</sub> **	Forward voltage drop	I <sub>F</sub> = 15 A	Tj = 25°C			3.6	V
			Tj = 125°C		2.1	2.6	

Pulse test: \* tp = 5ms,  $\delta$  < 2% \*\* tp = 380 $\mu$ s,  $\delta$  < 2%

To evaluate the maximum conduction losses use the following equation: P = 1.8 x  $I_{F(AV)}$  + 0.053 x  $I_{F}^{2}(RMS)$ 

#### **RECOVERY CHARACTERISTICS**

Symbol	Parameter	Tests Conditions		Min.	Тур.	Max.	Unit
trr	Reverse recovery time	$I_F = 0.5 \text{ A}$ $Irr = 0.25 \text{A}$ $Tj = 25^{\circ}\text{C}$ $I_R = 1 \text{ A}$			16		ns
		$I_F = 1 \text{ A } dI_F/dt = -50 \text{A}/\mu \text{s}$ $V_R = 30 \text{ V}$				35	
I <sub>RM</sub>	Reverse recovery	V <sub>R</sub> = 400 V I <sub>F</sub> = 15 A	Tj = 125°C		4.8	6.0	Α
S <sub>factor</sub>	current	$dI_F/dt = -200 A/\mu s$			0.4		-

### **TURN-ON SWITCHING CHARACTERISTICS**

Symbol	Parameter	$\begin{tabular}{ll} \textbf{Tests Conditions} \\ I_F = 15 \ A \ dI_F/dt = 100 A/\mu s, \\ V_{FR} = 1.1 \ x \ V_F max \\ \end{tabular} Tj = 25 ^{\circ} C$		Min.	Тур.	Max.	Unit
tfr	Forward recovery time					200	ns
V <sub>FP</sub>	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		Tj = 25°C			6	V

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Fig. 1: Conduction losses versus average current.

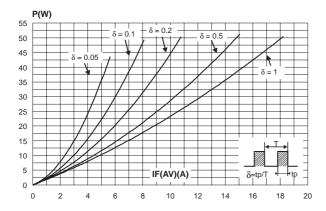
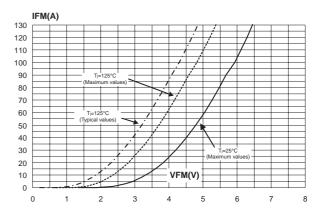


Fig. 2: Forward voltage drop versus forward current.



**Fig. 3:** Relative variation of thermal impedance junction to case versus pulse duration.

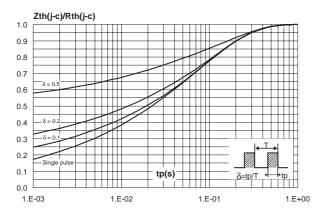


Fig. 4: Peak reverse recovery current versus  $dI_F/dt$  (90% confidence).

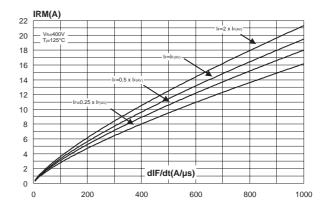
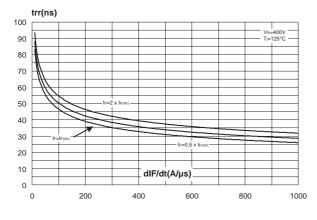
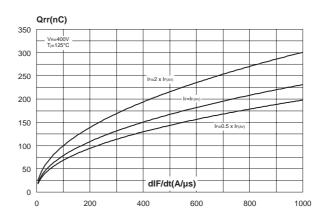


Fig. 5: Reverse recovery time versus dI<sub>F</sub>/dt (90% confidence).

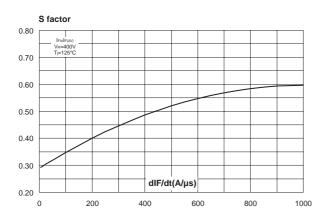


**Fig. 6:** Reverse recovery charges versus dI<sub>F/</sub>dt (90% confidence).

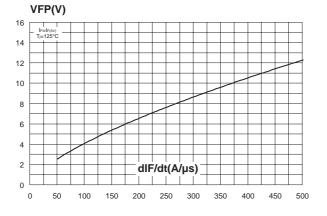


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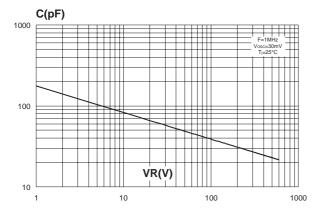
Fig. 7: Softness factor versus  $dI_F/dt$  (typical values).



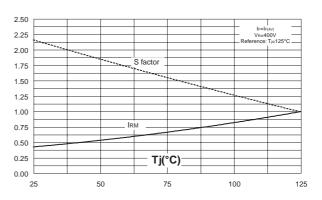
**Fig. 9:** Transient peak forward voltage versus dl<sub>F</sub>/dt (90% confidence).



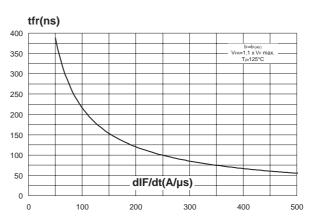
**Fig. 11:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 8:** Relative variations of dynamic parameters versus junction temperature.

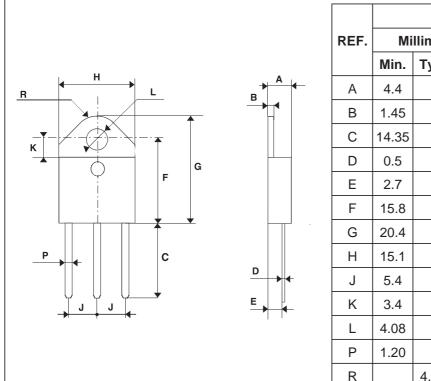


**Fig. 10:** Forward recovery time versus  $dI_F/dt$  (90% confidence).



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## PACKAGE MECHANICAL DATA



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	4.4		4.6	0.173		0.181	
В	1.45		1.55	0.057		0.061	
С	14.35		15.60	0.565		0.614	
D	D 0.5 E 2.7		0.7	0.020		0.028	
Е			2.9	0.106		0.114	
F	15.8		16.5	0.622		0.650	
G	20.4		21.1	0.815		0.831	
Н	15.1		15.5	0.594		0.610	
J	5.4		5.65	0.213		0.222	
K	3.4		3.65	0.134		0.144	
L	4.08		4.17	0.161		0.164	
Р	1.20		1.40	0.047		0.055	
R		4.60			0.181		

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH1506TPI	STTH1506TPI	TOP3I	4.46 g.	30	Tube

■ Epoxy meets UL94,V0

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